NSN 5961-00-509-5678

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View Online at https://aerobasegroup.com/nsn/5961-00-509-5678 **Inclosure Material:** Metal **Overall Length:** 0.295 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.440 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 550.0 collector to base voltage, dc and 510.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

Demilitarization: No

Unit Of Measure:

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